





EP36 45 ET

Series —
RoHS Compliant (Pb-free) 3.3V 4 Pad 3.2mm x 5mm
Ceramic SMD LVCMOS Programmable Oscillator

Storage Temperature Range

Frequency Tolerance/Stability ±50ppm Maximum

Operating Temperature Range – -40°C to +85°C

-55°C to +125°C

PD -19.200M

Nominal Frequency 19.200MHz

Pin 1 Connection
Power Down (Disable Output: Logic Low)

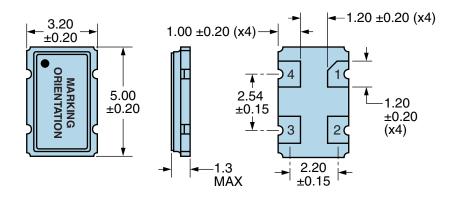
Duty Cycle 50 ±10(%)

ELECTRICAL SPECIFICA	ELECTRICAL SPECIFICATIONS		
Nominal Frequency	19.200MHz		
Frequency Tolerance/Stability	±50ppm Maximum (Inclusive of all conditions: Calibration Tolerance at 25°C, Frequency Stability over the Operating Temperature Range, Supply Voltage Change, Output Load Change, First Year Aging at 25°C, Shock, and Vibration)		
Aging at 25°C	±5ppm/year Maximum		
Operating Temperature Range	-40°C to +85°C		
Supply Voltage	3.3Vdc ±0.3Vdc		
Input Current	28mA Maximum (Unloaded)		
Output Voltage Logic High (Voh)	Vdd-0.4Vdc Minimum (IOH = -8mA)		
Output Voltage Logic Low (Vol)	0.4Vdc Maximum (IOL = +8mA)		
Rise/Fall Time	4nSec Maximum (Measured at 20% to 80% of waveform)		
Duty Cycle	50 ±10(%) (Measured at 50% of waveform)		
Load Drive Capability	30pF Maximum		
Output Logic Type	CMOS		
Pin 1 Connection	Power Down (Disable Output: Logic Low)		
Tri-State Input Voltage (Vih and Vil)	70% of Vdd Minimum to enable output, 20% of Vdd Maximum to disable output, No Connect to enable output.		
Standby Current	20μA Maximum (Pin 1 = Ground)		
Disable Current	16mA Maximum (Pin 1 = Ground)		
Absolute Clock Jitter	±250pSec Maximum, ±100pSec Typical		
One Sigma Clock Period Jitter	±50pSec Maximum		
Start Up Time	10mSec Maximum		

ENVIRONMENTAL & MECHANICAL SPECIFICATIONS		
Fine Leak Test	MIL-STD-883, Method 1014, Condition A	
Gross Leak Test	MIL-STD-883, Method 1014, Condition C	
Mechanical Shock	MIL-STD-202, Method 213, Condition C	
Resistance to Soldering Heat	MIL-STD-202, Method 210	
Resistance to Solvents	MIL-STD-202, Method 215	
Solderability	MIL-STD-883, Method 2003	
Temperature Cycling	MIL-STD-883, MEthod 1010	
Vibration	MIL-STD-883, Method 2007, Condition A	



MECHANICAL DIMENSIONS (all dimensions in millimeters)

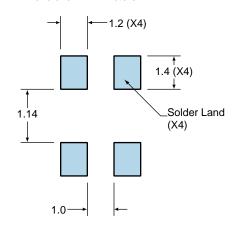


PIN CONNECTION		
1	Power Down (Logic Low)	
2	Ground/Case Ground	
3	Output	
4	Supply Voltage	

LINE	MARKING
1	E19.200 E=Ecliptek Designator

Suggested Solder Pad Layout

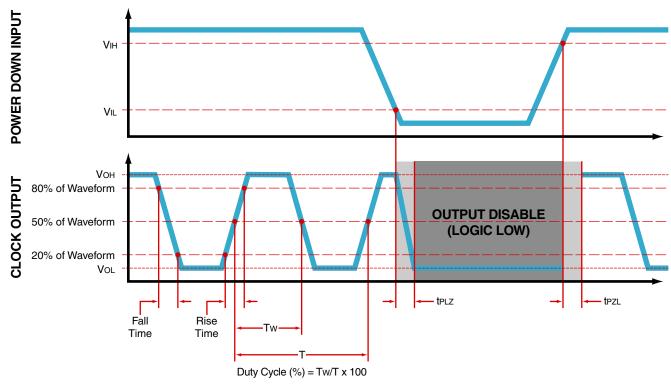
All Dimensions in Millimeters



All Tolerances are ±0.1



OUTPUT WAVEFORM & TIMING DIAGRAM



Test Circuit for CMOS Output



- Note 1: An external $0.1\mu F$ low frequency tantalum bypass capacitor in parallel with a $0.01\mu F$ high frequency ceramic bypass capacitor close to the package ground and V_{DD} pin is required.
- Note 2: A low capacitance (<12pF), 10X attenuation factor, high impedance (>10Mohms), and high bandwidth (>300MHz) passive probe is recommended.
- Note 3: Capacitance value \dot{C}_L includes sum of all probe and fixture capacitance.



Recommended Solder Reflow Methods



High Temperature Infrared/Convection

T _s MAX to T _∟ (Ramp-up Rate)	3°C/second Maximum
Preheat	
- Temperature Minimum (T _s MIN)	150°C
- Temperature Typical (T _s TYP)	175°C
- Temperature Maximum (T _S MAX)	200°C
- Time (t _s MIN)	60 - 180 Seconds
Ramp-up Rate (T _L to T _P)	3°C/second Maximum
Time Maintained Above:	
- Temperature (T∟)	217°C
- Time (t∟)	60 - 150 Seconds
Peak Temperature (T _P)	260°C Maximum for 10 Seconds Maximum
Target Peak Temperature (T _P Target)	250°C +0/-5°C
Time within 5°C of actual peak (tp)	20 - 40 seconds
Ramp-down Rate	6°C/second Maximum
Time 25°C to Peak Temperature (t)	8 minutes Maximum
Moisture Sensitivity Level	Level 1



Recommended Solder Reflow Methods



Low Temperature Infrared/Convection 240°C

T _S MAX to T _L (Ramp-up Rate)	5°C/second Maximum
Preheat	
- Temperature Minimum (T _s MIN)	N/A
- Temperature Typical (T _s TYP)	150°C
- Temperature Maximum (T _s MAX)	N/A
- Time (t _s MIN)	60 - 120 Seconds
Ramp-up Rate (T _L to T _P)	5°C/second Maximum
Time Maintained Above:	
- Temperature (T∟)	150°C
- Time (t∟)	200 Seconds Maximum
Peak Temperature (T _P)	240°C Maximum
Target Peak Temperature (T _P Target)	240°C Maximum 1 Time / 230°C Maximum 2 Times
Time within 5°C of actual peak (t _p)	10 seconds Maximum 2 Times / 80 seconds Maximum 1 Time
Ramp-down Rate	5°C/second Maximum
Time 25°C to Peak Temperature (t)	N/A
Moisture Sensitivity Level	Level 1

Low Temperature Manual Soldering

185°C Maximum for 10 seconds Maximum, 2 times Maximum.

High Temperature Manual Soldering

260°C Maximum for 5 seconds Maximum, 2 times Maximum.